COMPLIANT

HALOGEN

FREE



Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	20 A						
V _R	15 V						
V _F at I _F	See Electrical table						
I _{RM} max.	600 mA at 100 °C						
T _J max.	125 °C						
E _{AS}	10 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- · Single diode configuration
- · Optimized for OR-ing applications
- Ultra low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	Α					
V_{RRM}		15	V					
I _{FSM}	$t_p = 5 \mu s sine$	700	Α					
V_{F}	19 A _{pk} , T _J = 125 °C (typical)	0.25	V					
T _J	Range	-55 to +125	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20L15T-M3	UNITS					
Maximum DC reverse voltage	V_{R}	15	V					
Maximum working peak reverse voltage	V_{RWM}	15	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C,	20					
Maximum peak one cycle non-repetitive surge current	o po onto or o po root. Pareo a root and a root of the		700	Α				
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH		10	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	2	Α				



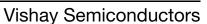
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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS		
		19 A	T _{.1} = 25 °C	ı	0.41	V		
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	11 = 23 0	•	0.52			
See fig. 1	VFM (')	19 A	T _{.1} = 125 °C	0.25	0.33			
		40 A	1J = 125 C	0.37	0.50			
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	-	10	mA		
See fig. 2	IRM (*)	T _J = 100 °C	v _R = nateu v _R	-	600	IIIA		
Threshold voltage	V _{F(TO)}	$T_1 = T_1 \text{ max.}$		0.182		V		
Forward slope resistance	r _t	ij = ij max.	7.6		mΩ			
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal ran	-	2000	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs			

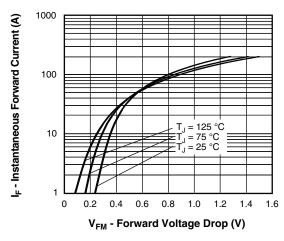
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	T_J		-55 to +125	°C				
Maximum storage temperature range	T _{Stg}		-50 to +150	C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50 °C/					
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40					
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum		Non-lubricated tilleads	12 (10)	(lbf·in)				
Marking device		Case style TO-220AC 2L	20L1	5T				







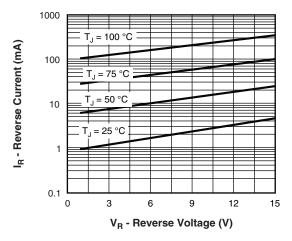


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

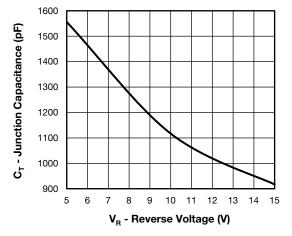


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

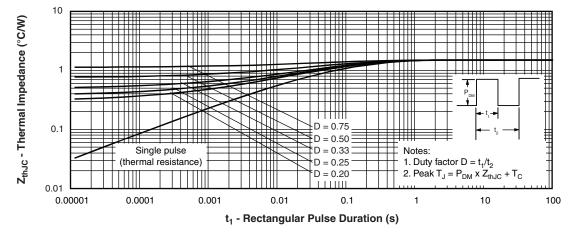


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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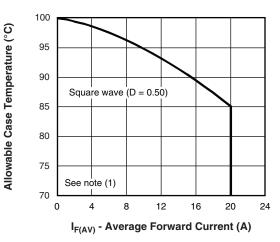


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

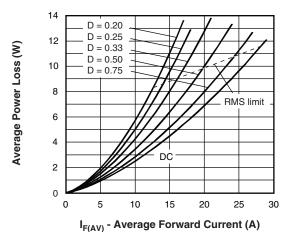


Fig. 6 - Forward Power Loss Characteristics

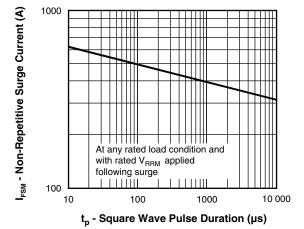


Fig. 7 - Maximum Non-Repetitive Surge Current

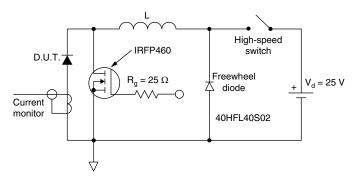


Fig. 8 - Unclamped Inductive Test Circuit

Note

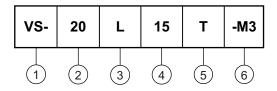
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 = 20 A)

3 - Schottky "L" series

- Voltage code (15 = 15 V)

5 - Package

T = TO-220

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-20L15T-M3	50	Antistatic plastic tubes					

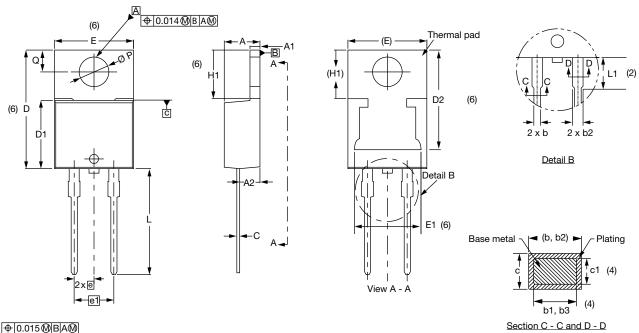
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96156						
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?97117					

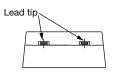


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TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7	
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6	
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6	
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105		
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208		
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6	
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552		
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2	
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154		
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118		
D1	8.38	9.02	0.330	0.355				•	•				

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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